



## Structural and Optical Properties of Bismuth-doped ZnO Nanoparticles Synthesized by Co-precipitation

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### PAPER INFO

#### Paper history:

Received 10 August 2022

Received in revised form 28 August 2022

Accepted 18 September 2022

#### Keywords:

Zinc Oxide Nanoparticles

Bismuth-doped ZnO

Co-precipitation

Photo-catalyst

### ABSTRACT

Bismuth-doped zinc oxide (ZnO) nanoparticles can serve as efficient photocatalysts for various reactions. Herein, we synthesized and discussed the growth mechanisms of Bi-doped ZnO nanoflakes using co-precipitation with Bi concentrations ranging from 0 to 3 %. The resulting ZnO were hexagonal nanosheets with diameters ranging from 80 nm (ZnO) to 200 nm (ZnO: Bi 3%). The dominant crystal structure matches hexagonal wurtzite with a small presence of Bi<sub>2</sub>O<sub>3</sub> diffraction peaks. The estimated crystallite sizes range from ~ 33 nm to ~ 45 nm, indicating multiple crystalline regions in each nanoflake. Nevertheless, as sheet resistance monotonically decreases with the Bi concentration, the higher number of grain boundaries likely has a lower effect on the conductivity compared to an increase in free carriers and larger grain size in the samples with higher Bi concentration. The bandgap decreases from ~ 3.13 eV to ~ 2.96 eV, likely due to the shrinkage effect from electron-electron or electron-impurity interaction that lowers the conduction band of ZnO.

doi: 10.5829/ije.2022.35.12c.10

### NOMENCLATURE

|          |                   |           |   |
|----------|-------------------|-----------|---|
| D        | Crystallite size  | $\lambda$ | Wavelength of the X-ray                     |
| $\theta$ | Diffracting angle | $\beta$   | Full-width half-max of the diffracting peak |

## 1. INTRODUCTION

Zinc oxide (ZnO) has been one of the most versatile materials with applications ranging from optoelectronics to photocatalysis. Among different forms of ZnO, nanoparticles can provide a higher surface area, which increases the number of active sites for the reactions compared to thin films or other 2D bulk surfaces, particularly useful for catalytic applications [4]. ZnO nanoparticles have been prepared by various techniques, including sol-gel method [5], electrophoretic deposition [6], hydrothermal methods [7], thermal decomposition [8, 9], chemical vapor deposition [10], and co-precipitation [11]. Co-precipitation is considered one of the most straightforward and affordable techniques due to its minimal setup and fewer chemical precursors involved in the process; while also allowing for

incorporating dopants to vary the electronic properties [12].

Since the surface area of the nanoparticles can highly influence the catalytic performance, different morphologies of the ZnO nanoparticles have been investigated, including nanorods [13], nanospheres [9], nanoplates [14], and nanowires [15]. In particular, ZnO nanosheets have been reported to exhibit better catalytic performance because of their higher number of polar facets [16, 17], which would likely be beneficial to reactions in aqueous solutions.

In addition, to further improve the photocatalytic activity of the ZnO nanoparticles, dopants are typically introduced to increase the absorption as well as potentially enhance the charge transfer on the surface. Particularly, bismuth has been used in catalytic applications, either as the cation in mixed oxide catalysts [18], or the dopant [3]. Bi dopant has been reported to

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lower the bandgap of ZnO nanocatalysts [19] and accelerate the interfacial electron transfer process, thus enhancing the photocatalytic activity under UV illumination [3]. Nevertheless, the growth mechanisms of Bi-doped ZnO nanosheet using co-precipitation is still not well investigated.

Herein, we present an investigation of the structural and optical properties of Bi-doped ZnO nanoparticles using a simple co-precipitation technique. Specifically, the procedure was optimized to produce hexagonal ZnO nanosheets. We also further discuss the formation mechanisms of these particles as well as the possible factors affecting the optoelectronic properties of the ZnO samples.

## 2. MATERIALS AND METHODS

All chemicals were used as received, including zinc acetate hydrate ( $\text{Zn}(\text{CH}_3\text{COO})_2 \cdot 2\text{H}_2\text{O}$ , AR Grade), bismuth nitrate pentahydrate ( $\text{BiN}_3\text{O}_9 \cdot 5\text{H}_2\text{O}$ , AR Grade), sodium hydroxide (NaOH, AR Grade), ethanol ( $\text{C}_2\text{H}_6\text{O}$ ). Deionized water with a resistivity  $\rho > 18 \text{ M}\Omega \cdot \text{cm}$  was used for the dilution processes. The zinc precursors were prepared using 0.5M of zinc acetate hydrate. For the dopant, bismuth nitrate pentahydrate was introduced to the zinc solution ranging from 0 to 3 wt% weighed using a high-precision digital scale with a sensitivity of 0.001 g, then rigorously mixed at room temperature for 15 min.

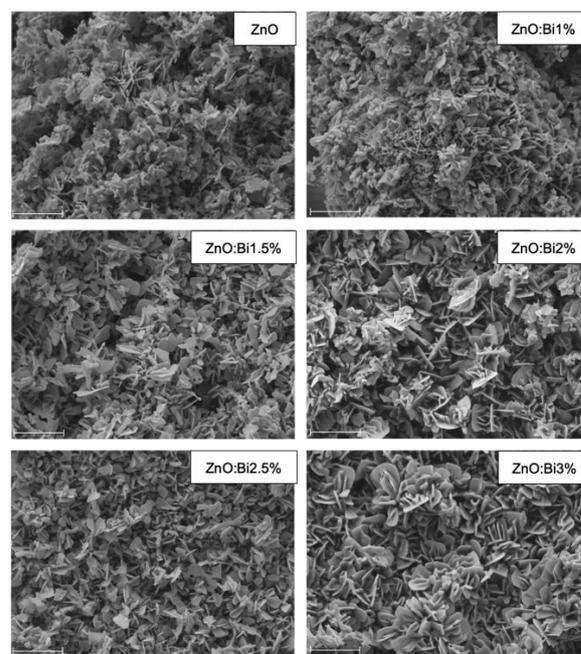
To initiate the co-precipitation process, 2.5M NaOH was gradually dropped into the zinc-bismuth solution while continuously stirring until the mixture reached pH = 13. The pH was monitored using a pH meter with a sensitivity of pH = 0.01, and the value was allowed to stabilize for 30 s after each NaOH addition. The solution was kept stirred for 15 min at room temperature. The precipitate was rigorously rinsed with DI water, vacuum dried, and rinsed again with ethanol before annealed at 80°C for 8 hours, then heated at 550°C for 2 hours to form zinc oxide nanoparticles.

The samples were then characterized for their optical and structural properties. Scanning electron micrographs (SEMs) were obtained with a Carl Zeiss AURIGA at an accelerating voltage of 3.00 kV with a working distance of 7.5 mm. X-ray Diffractometry (XRD) was performed using Bruker D2 Phaser with a Cu  $K\alpha$  monochromator with an x-ray wavelength of 1.54060 Å using 2 $\theta$  angles ranging from 10° to 90°. UV-Vis spectrometer was utilized to obtain the absorption spectra at the wavelength ranging from 200 nm to 1000 nm.

For sheet resistance measurement, the nanoparticles were screen painted onto 1x1 cm glass slides and were characterized using Jandel RM3-AR four-point probe with an operating current of 10 mA.

## 3. RESULTS AND DISCUSSION

As-synthesized ZnO nanoparticles were first inspected for surface morphology. Figures 1(a)-1(f) show the SEM images of ZnO samples with bismuth concentration of (a) 0 %, (b) 1 %, (c) 1.5 %, (d) 2 %, (e) 2.5 % and (f) 3 %. In all concentrations, the ZnO nanoparticles were formed into hexagonal nanoflakes, showing higher contrast, and sharper morphology as the bismuth concentration increased, with the average flake diameter ranging from 80 nm (ZnO) to 200 nm (ZnO: Bi 3%). The hexagonal shape of the particle is likely due to the preferred deposition along the *a*-axis of the ZnO lattice as supposed to the other common nanorod where the deposition would be preferred along the *c*-axis. Only the local structure and the facet of the particles were assumed to have any effects on the growth orientation. The transport of the precursor ion could potentially affect the growth, but were assumed to have a minimal influence in this environment. This preferential deposition along the *a*-axis can most likely be attributed to the strong local environment (pH = 13) around the initial nucleation site of the particle, where the excess OH leads to the formation of zinc hydroxide complex  $\text{Zn}(\text{OH})_4^{2-}$  from the  $\text{Zn}^{2+}$ , that was dissociated from the zinc acetate hydrate precursor. The negatively charged zinc hydroxide complex was then repelled from the negative surface of ZnO along the *c*-axis (100) orientation, thus resulting in more prominent 2D hexagonal flakes. This preferential growth on the 2D



**Figure 1.** Scanning electron micrographs of ZnO with Bi concentration ranging from 0% to 3%, with the scalebar representing 1  $\mu\text{m}$

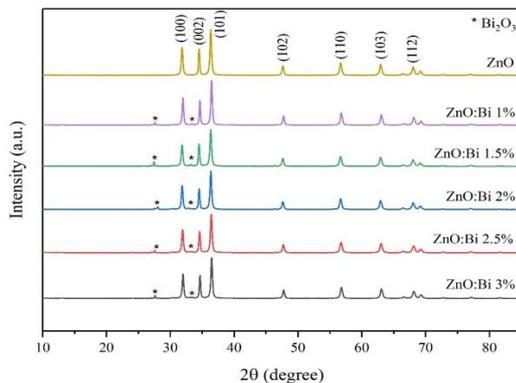
plane is also likely more observable in the co-precipitation technique, where the deposition mechanisms rely heavily on diffusion and adsorption of the precursors.

In addition, larger hexagonal flakes and the shaper 2D morphology were observed as higher Bi concentration was introduced. The positively charged  $\text{Bi}^{3+}$  from the bismuth nitrate precursor likely creates a more favorable local deposition environment at the ZnO sites, assisting the oxidation of the zinc hydroxide complex around the edge of the nanosheet. This preferred deposition can also be observed from having less residual deposition in other orientations in the samples with lower Bi concentration (Figure 1: ZnO and ZnO: Bi1%).

Figure 2 shows XRD patterns of the as-prepared Bi-doped ZnO nanoparticles with different Bi concentrations. The peaks at  $2\theta \approx 27.5^\circ$  and  $\sim 33.2^\circ$  represent the  $\text{Bi}_2\text{O}_3$  peaks which can be observed in all samples except ZnO with no Bi dopant [20]. The main diffracting peaks were observed for the (100), (002), and (101) orientation of wurtzite ZnO at  $2\theta = 31.8^\circ$ ,  $34.6^\circ$ , and  $36.4^\circ$ , respectively, with the remaining peaks corresponding to the (102), (110), (103), and (112) orientation [21]. The locations of the diffraction peaks match precisely with the standards as well as the ZnO particles with different morphology and different preparation techniques [9]. The intensities of the diffraction peaks are all comparable even with increasing Bi concentration, indicating that the amount of the Bi dopant in the lattice is not sufficient to have any effect on the overall crystal structure of the ZnO host. The intensity of the (002) peak is comparable to that of (100), suggesting growth along the planar axis, [22] which is in good accord with the observed morphology (Figure 1).

Table 1 summarizes the crystallite size ( $D$ ) estimated from the XRD pattern (Figure 2) using Scherrer's equation:

$$D = \frac{0.94\lambda}{\beta \cos \theta} \quad (1)$$



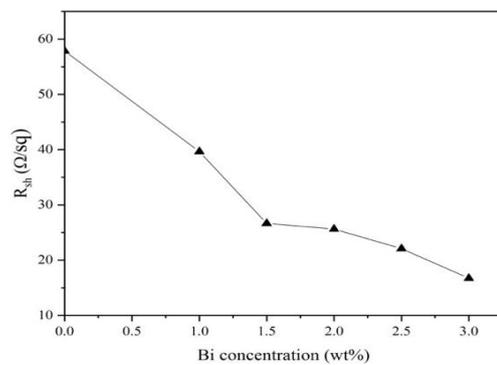
**Figure 2.** X-ray diffractometry patterns of Bi-doped ZnO with Bi concentration 0% to 3%

**TABLE 1.** Estimated crystallite size using Scherrer's equation

| ZnO:Bi (%) | Crystalline size (nm) |
|------------|-----------------------|
| 0          | 33.58                 |
| 1          | 41.79                 |
| 1.5        | 41.95                 |
| 2          | 42.06                 |
| 2.5        | 42.53                 |
| 3          | 44.65                 |

where  $\lambda$  is the x-ray wavelength,  $\beta$  is the full-width half max (FWHM), and  $\theta$  is the Bragg diffraction angle. The crystallite size monotonically increases with the Bi concentration, agreeing with more favorable deposition environment under the presence of  $\text{Bi}^{3+}$  cation. Nevertheless, the crystallite size is still substantially smaller than the size of each hexagonal nanoflake (Figure 1), suggesting that each flake may consist of multiple crystallites. Moreover, the average diameter of the flake increases by more than twice from  $\sim 80$  nm to  $\sim 200$  nm, while the estimated crystallite size increases from  $\sim 33$  nm to  $\sim 45$  nm, indicating that new nucleation sites on each nanosheet could be developed during the deposition, especially on the larger flakes and higher Bi concentration.

In addition, the distribution of the crystalline region in the sample also has a strong influence on the resistance. Since electronic conduction relies predominantly on the transport of free carriers in the sample, larger grain size typically leads to lower sheet resistance, while grain boundaries between multiple crystallites usually increase the sheet resistance. Figure 3 shows the sheet resistance of the ZnO nanoparticles with different Bi concentrations. The measured resistance monotonically decreases from  $\sim 58 \Omega \text{ sq}^{-1}$  in an undoped ZnO to  $\sim 20 \Omega \text{ sq}^{-1}$  in the 3%-doped ZnO. The reduction in sheet resistance with higher Bi concentration is likely



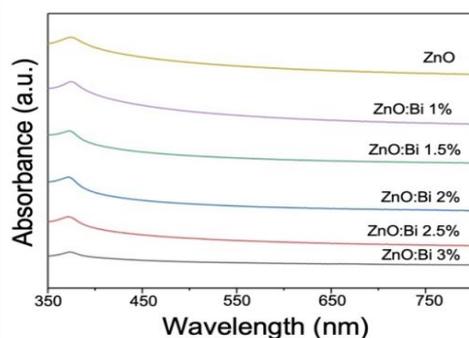
**Figure 3.** Sheet resistance of the ZnO nanoparticles as a function of Bi concentrations

due to an increase in free electrons from  $\text{Bi}^{3+}$  donors in the lattice. Although the conductivity was previously reported to decrease at specific Bi concentrations because of the segregation of Bi atoms at the grain boundaries [23], the monotonic decrease in the observed resistance suggests that the Bi concentration used in this experiment is still low or the grain boundary resistance is negligible at this scale.

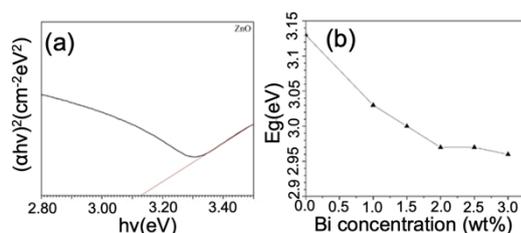
The absorbance of the nanoparticles was measured with the wavelength sweeping from 350 nm to 800 nm, shown in Figure 4, which gradually increases and peaks at  $\sim 370$  nm for all samples, then slowly decreases to the baseline. Similar peak positions at  $\sim 370$  nm have also been observed in other study as the hexagonal wurtzite phase [24]. These absorbance spectra were then used to calculate the bandgap of the ZnO samples with Tauc relation [25]:

$$\alpha h\nu = E(h\nu - E_g)^{\frac{1}{2}} \quad (2)$$

where  $\alpha$  is the optical absorption coefficient from Figure 4,  $h\nu$  is the photon energy,  $E_g$  is the bandgap,  $E$  is a fitting constant, and the power of  $\frac{1}{2}$  indicating direct bandgap transition of ZnO. Figure 5(a) shows the example Tauc plot using the absorption from the undoped ZnO sample, with the straight line extrapolated from the right regime of the curve and the x-intercept of this line representing the derived bandgap of the material. Figure 5(b) shows the calculated bandgap with varying Bi



**Figure 4.** Absorbance of the ZnO nanoparticles as a function of wavelength



**Figure 5.** (a) Tauc plot of ZnO nanoparticles and (b) Bandgap of the ZnO nanoparticles as a function of Bi concentrations

concentration, where the bandgap decreases sharply from 0 % to 2 %, then remains relatively constant between 2 % to 3 %. The decrease can primarily be attributed to the shrinkage effect, which results in a lowering of the conduction band due to the net attractive interaction between electron-electron and electron-impurity interaction. Nevertheless, the more minor change after 2% dopant is likely due to fluctuation that comes from both the broadening of the valence band as well as the lowering of the conduction band [26–28].

#### 4. CONCLUSIONS

Bi-doped ZnO nanoparticles were successfully prepared using co-precipitation using minimal laboratory setup. The morphology of the nanoparticles reveals that hexagonal nanosheets were produced, mostly by maintaining high alkalinity of the solution, with the average diameter increasing from 80 nm to 200 nm with higher Bi concentration. The wurtzite structure was observed, with the average crystallite size ranging from  $\sim 33$  nm to  $\sim 45$  nm, suggesting multiple crystalline regions in each nanoflake. Nevertheless, grain boundary resistance likely has minimal effect on the conductivity of the free carriers in these particles, as the sheet resistance decreases monotonically with the dopant concentration. The decrease in the optical bandgap with higher Bi concentration is likely due to the shrinkage effect from the electron-electron and electron-impurity interaction that leads to the lowered conduction band. However, the decrease of the bandgap gradually diminishes as the Bi concentration is  $> 2$  %. These results show co-precipitation as a viable technique to synthesize Bi-doped ZnO nanosheets that exhibit optoelectronic and structural properties similar to those prepared using more sophisticated techniques. Nevertheless, further precise optimization of the electronic properties such fine-tuning the absolute band edge positions might require a more advance technique such as chemical vapor deposition.

#### 5. ACKNOWLEDGMENT

This project is based upon work performed within the Physics and General Science Program, supported through the Faculty of Science and Technology's 2020 Departmental Funding. P.B. would like to acknowledge Warisa Ketphan for advice on figure preparation.

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## Persian Abstract

## چکیده

نانوذرات اکسید روی دوپ شده با بیسموت (ZnO) می‌توانند به عنوان فوتوکاتالیست کارآمد برای واکنش‌های مختلف عمل کنند. در اینجا، ما مکانیسم‌های رشد نانوفلک‌های اکسید روی دوپ‌شده را با استفاده از رسوب همزمان با غلظت‌های بی از ۰ تا ۳ درصد سنتز و مورد بحث قرار دادیم. ZnO حاصل، نانوصفحات شش ضلعی با قطرهای ۸۰ نانومتر (ZnO) تا ۲۰۰ نانومتر (ZnO: Bi 3%) بود. ساختار کریستالی غالب با ورتزیت شش ضلعی با حضور کمی از قله‌های پر اش Bi<sub>2</sub>O<sub>3</sub> مطابقت دارد. اندازه کریستالیت تخمین زده شده از ۳۳ نانومتر تا ۴۵ نانومتر متغیر است که نشان دهنده چندین ناحیه کریستالی در هر نانوفلک است. با این وجود، از آنجایی که مقاومت ورق به طور یکنواخت با غلظت Bi کاهش می‌یابد، تعداد بیشتر مرزهای دانه احتمالاً تأثیر کمتری بر هدایت در مقایسه با افزایش حامل‌های آزاد و اندازه دانه بزرگتر در نمونه‌های با غلظت Bi بالاتر دارد. فاصله باند از ~۳.۱۳ eV به ~۲.۹۶ eV کاهش می‌یابد، که احتمالاً به دلیل اثر انقباض ناشی از برهمکنش الکترون-الکترون یا الکترون-ناخالصی است که نوار رسانایی ZnO را کاهش می‌دهد.